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IFD

Atty. Dkt. No. 039153-0688

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

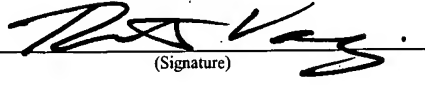
Applicant: Ihsan J. DJOMEHRI
Title: STRAINED SILICON MOSFETS
HAVING NMOS GATES WITH
WORK FUNCTIONS FOR
COMPENSATING NMOS
THRESHOLD VOLTAGE SHIFT

Appl. No.: 10/738,496

Filing Date: 12/17/2003

Examiner: V. Hung

Art Unit: 2811

CERTIFICATE OF EXPRESS MAILING	
I hereby certify that this correspondence is being deposited with the United States Postal Service's "Express Mail Post Office To Addressee" service under 37 C.F.R. § 1.10 on the date indicated below and is addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.	
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Ruthie Vallejo (Printed Name)	
 (Signature)	

RESPONSE TO ELECTION REQUIREMENT

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the restriction requirement set forth in the Office Action mailed December 3, 2004, Applicant hereby provisionally elects Embodiment 1 of Figures 5a-5f. Claims 9-12 read on this embodiment. Applicant reserves the right to file a divisional application on the non-elected claims.

Respectfully submitted,

Date 14 December 2004By Ronald Coslick

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